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March 2015



FGB20N60SFD 600 V, 20 A Field Stop IGBT

Features

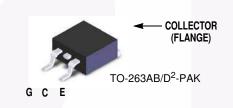
- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 2.2 V @ I_C = 20 A
- High Input Impedance
- Fast Switching : E_{OFF} = 8 uJ/A
- RoHS Compliant

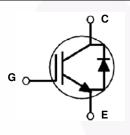
Applications

• Solar Inverter, UPS, Welder, PFC

General Description

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Descriptio	n	Ratings	Unit	
V _{CES}	Collector to Emitter Voltage		600	V	
V	Gate to Emitter Voltage		±20	V	
V _{GES} Transient Gate-to-Emitter Voltage			±30	V	
I _C	Collector Current	@ T _C = 25°C	40	A	
10	Collector Current	@ T _C = 100 ^o C	20	A	
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25°C	60	A	
IF	Diode Forward Current	@ T _C = 25°C	20	А	
Diode Forward Current		@ T _C = 100°C	10	А	
I _{FM(1)}	Pulsed Diode Maximum Forward Current		60	A	
P _D	Maximum Power Dissipation	@ T _C = 25°C	208	W	
. D	Maximum Power Dissipation	@ T _C = 100°C	83	W	
Т _Ј	Operating Junction Temperature		-55 to +150	°C	
T _{stg}	Storage Temperature Range		-55 to +150	°C	
Τ _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	0.6	°C/W
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	-	2.6	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)	-	40	°C/W

Notes: 2: Mounted on 1" square PCB (FR4 or G-10 material)

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGB20N60SFD	FGB20N60SFD	D ² -PAK	Reel	13" Dia	N/A	800

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	V _{GE} = 0 V, I _C = 250 μA	600	-	-	V
ΔBV_{CES} / ΔT_J	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0 V, I_C = 250 \mu A$	-	0.6	-	V/ºC
ICES	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$	-	-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	I _C = 250 μA, V _{CE} = V _{GE}	4.0	5.0	6.5	V
02()		$I_{\rm C} = 20$ A, $V_{\rm GE} = 15$ V	-	2.2	2.8	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	$I_{\rm C}$ = 20 A, $V_{\rm GE}$ = 15 V, $T_{\rm C}$ = 125°C	-	2.4	-	V
Dynamic C	characteristics					
C _{ies}	Input Capacitance		-	940	-	pF
C _{oes}	Output Capacitance	V _{CE} = 30 V _, V _{GE} = 0 V, f = 1 MHz	-	110	-	pF
C _{res}	Reverse Transfer Capacitance			40	-	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time			13	-	ns
t _r	Rise Time		-	16	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 20 A,	-	90	-	ns
t _f	Fall Time	R _G = 10 Ω, V _{GE} = 15 V,	-	24	48	ns
Eon	Turn-On Switching Loss	Inductive Load, T _C = 25°C	-	0.37	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.16	-	mJ
E _{ts}	Total Switching Loss	-	-	0.53	-	mJ
t _{d(on)}	Turn-On Delay Time		-	12	-	ns
t _r	Rise Time		-	16	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 20 A,	-	95	-	ns
t _f	Fall Time	$R_{G} = 10 \Omega, V_{GE} = 15 V,$	-	28	-	ns
Eon	Turn-On Switching Loss	Inductive Load, T _C = 125°C	-	0.4	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.28	-	mJ
E _{ts}	Total Switching Loss]	-	0.69	-	mJ

Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

Qg	Total Gate Charge		-	65	-	nC
Q _{ge}	Gate to Emitter Charge	V _{CE} = 400 V, I _C = 20 A, V _{GE} = 15 V	-	7	-	nC
Q _{gc}	Gate to Collector Charge	VGE - 13 V	-	33	-	nC

Electrical Characteristics of the Diode $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Test Condition	าร	Min.	Тур.	Max	Unit
V _{FM} Diode Forward Voltage	Diode Forward Voltage	I _F = 10 A	10 A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	1.9	2.5	V
	1F = 10 / 1	T _C = 125°C	-	1.7	-			
t	t _{rr} Diode Reverse Recovery Time	I _F =10 A, di _F /dt = 200 A/μs	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	34	-	ns	
41			$T_{\rm C} = 125^{\rm o}{\rm C}$	-	57	-		
Q.,,	Q _{rr} Diode Reverse Recovery Charge	ч <u>н</u> — 1	$10.70, 00F/00 = 200 P/\mu 3$	$T_{C} = 25^{\circ}C$	-	41	-	nC
~11				$T_{C} = 125^{\circ}C$	-	96	-	

Typical Performance Characteristics



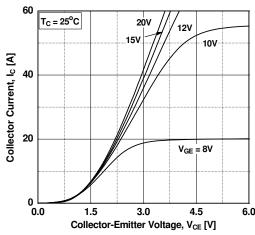


Figure 3. Typical Saturation Voltage Characteristics

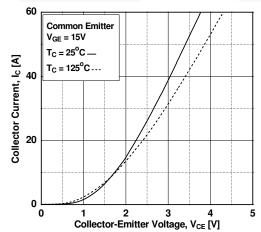


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

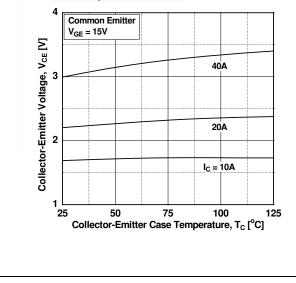


Figure 2. Typical Output Characteristics

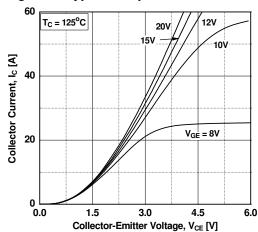


Figure 4. Transfer Characteristics

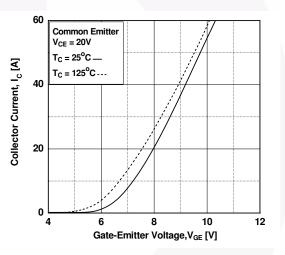
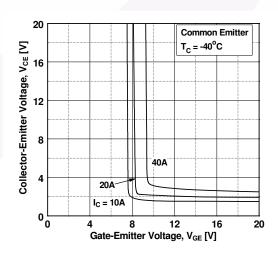
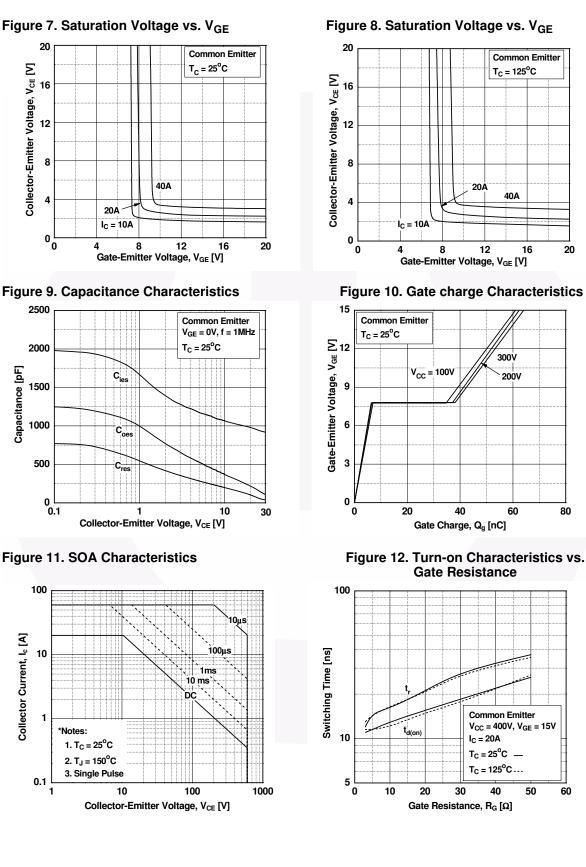


Figure 6. Saturation Voltage vs. V_{GE}





Typical Performance Characteristics

Figure 8. Saturation Voltage vs. V_{GE}

8

40

Common Emitter

T_C = 125°C

40A

300V

200

60

Common Emitter

I_C = 20A

30

 $T_{C} = 25^{\circ}C$ –

T_C = 125°C

40

V_{CC} = 400V, V_{GE} = 15V

50

60

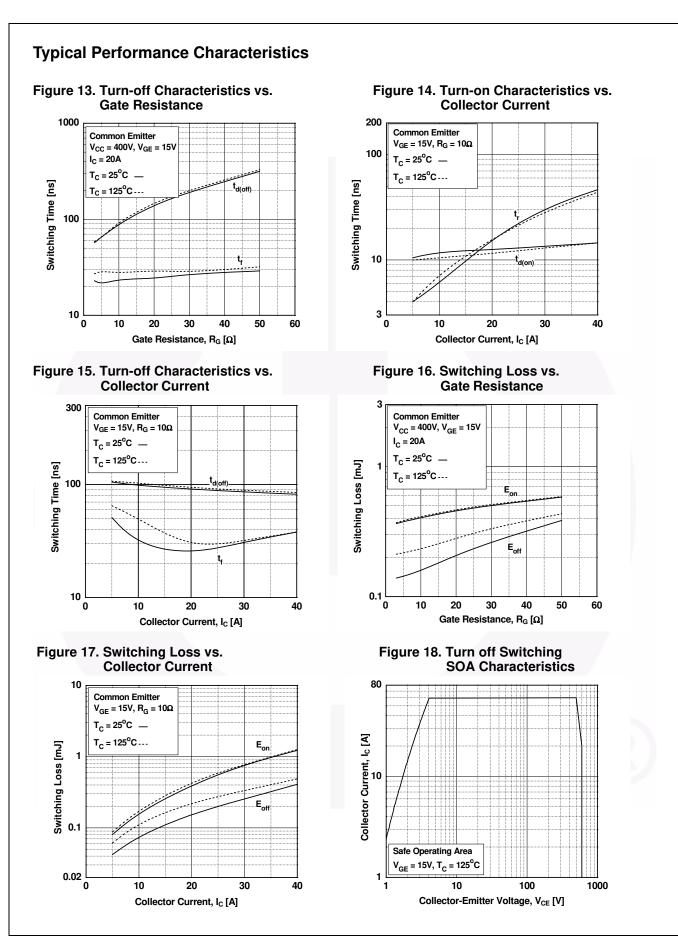
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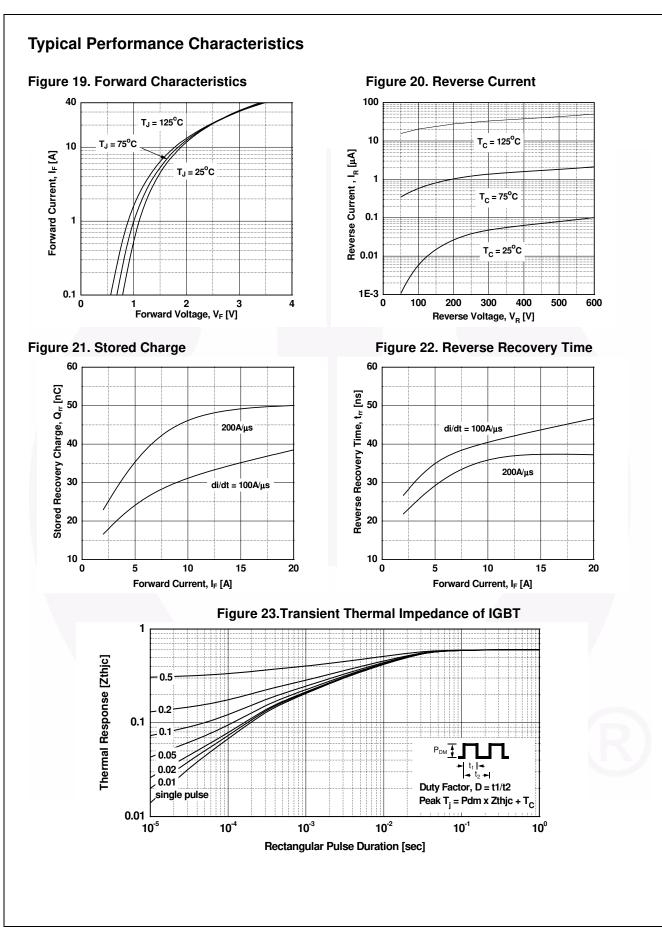
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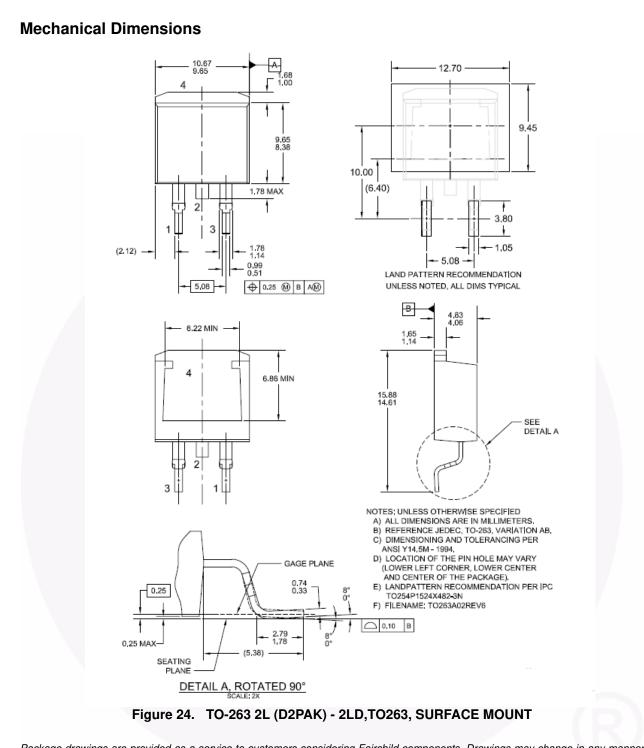
20A

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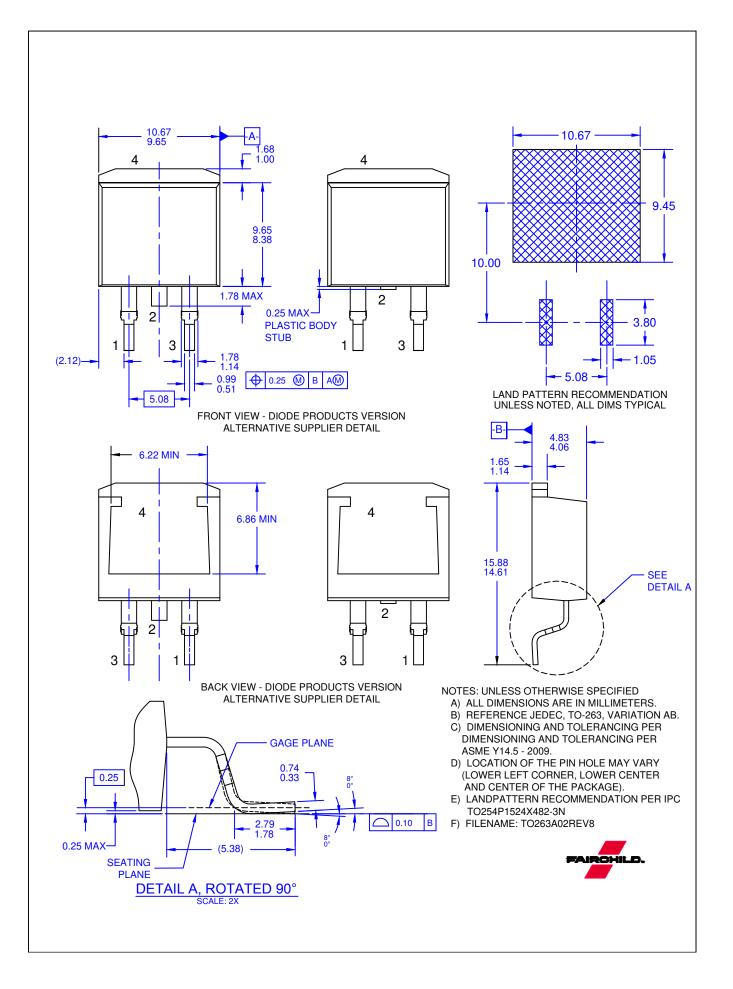
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